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Rohm Semiconductor 2SK2740

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Transistors

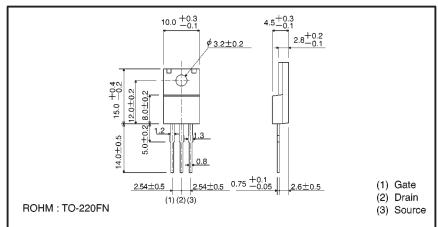
Switching (600V, 7A) 25K2740

Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- 4) Gate-source voltage (V_{GSS}) guaranteed to be ±30V.
- 5) Easily designed drive circuits.
- 6) Easy to parallel.

●Structure Silicon N-channel MOSFET

External dimensions (Units: mm)



● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		Voss	600	V
Gate-source voltage		Vgss	±30	V
Drain current	Continuous	lo	7	Α
	Pulsed	IDP*	28	Α
Reverse drain current	Continuous	Idr	7	А
	Pulsed	lorp*	28	Α
Total power dissipation(Tc=25℃)		Po	30	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55~+150	င

^{*} Pw \leq 10 μ s, Duty cycle \leq 1%

Packaging specifications

	Package	Bulk
Туре	Code	_
	Basic ordering unit (pieces)	500
2SK2740		0



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●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Gate-source leakage	Igss	_	_	±100	nA	V _{GS} =±30V, V _{DS} =0V
Drain-source breakdown voltage	V(BR)DSS	600	_	_	٧	ID=1mA, VGS=0V
Zero gate voltage drain current	IDSS	_	_	100	μΑ	V _{DS} =600V, V _{GS} =0V
Gate threshold voltage	VGS(th)	2.0	_	4.0	٧	V _{DS} =10V, I _D =1mA
Static drain-source on-state resistance	RDS(on)	_	1.0	1.2	Ω	ID=4A, VGS=10V
Forward transfer admittance	Yfs *	3.0	6.0	_	S	In=4A, Vns=10V
Input capacitance	Ciss	_	1050	_	рF	V _{DS} =10V
Output capacitance	Coss	_	210	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	80	_	рF	f=1MHz
Turn-on delay time	td(on)	_	19	_	ns	ID=4A, VDD≒150V
Rise time	tr	_	22	_	ns	V _{GS} =10V
Turn-off delay time	td(off)	_	79	_	ns	RL=37.5Ω
Fall time	tr	_	30	_	ns	R _G =10 Ω
Reverse recovery time	trr	_	590	_	ns	IDR=7A, VGS=0V
Reverse recovery charge	Qrr	_	4.6	_	μC	di/dt=100A/ μs

^{*} Pw≤300 μ s, Duty cycle≤1%

Electrical characteristic curves

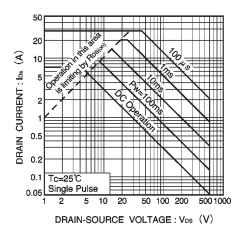


Fig.1 Maximum safe operating area

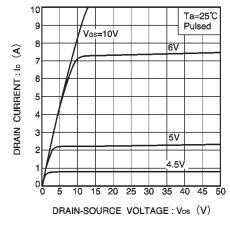


Fig.2 Typical output characteristics

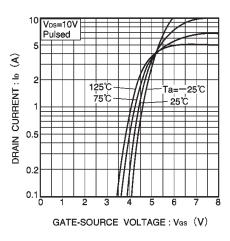
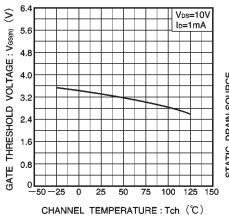
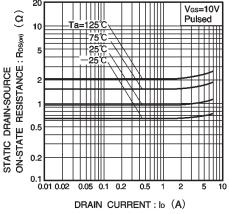


Fig.3 Typical transfer characteristics







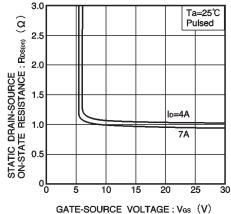
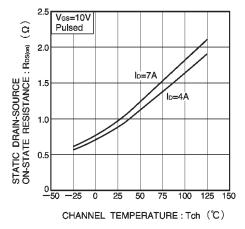
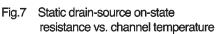


Fig.4 Gate threshold voltage vs. channel temperature

Fig.5 Static drain-source on-state resistance vs. drain current

Fig.6 Static drain-source on-state resistance vs. gate-source voltage





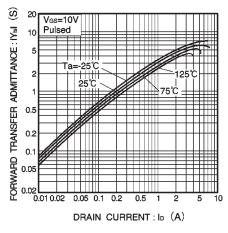


Fig.8 Forward transfer admittance vs. drain current

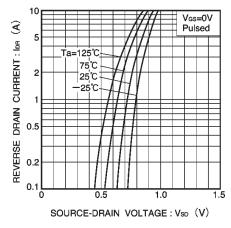


Fig.9 Reverse drain current vs. source-drain voltage (I)

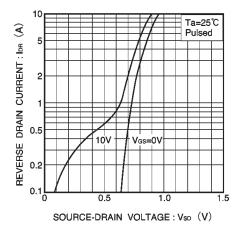


Fig.10 Reverse drain current vs. source-drain voltage (I)

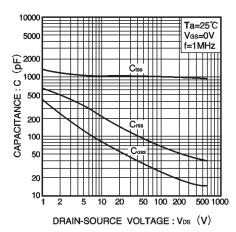


Fig.11 Typical capacitance vs. drain-source voltage

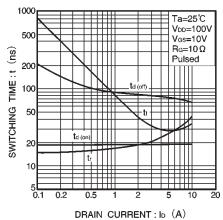


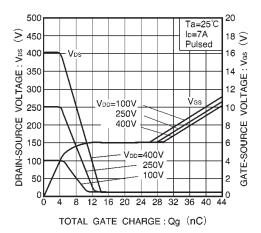
Fig.12 Switching characteristics (See Figures 16 and 17 for the measurement circuit and resultant waveforms)

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Ta=25°C di/dt=100A/ μs Vas=0V Pulsed Pulsed

Fig.13 Dynamic input characteristics (See Figure 18 for

measurement circuit)

Fig.14 Reverse recovery time vs. reverse drain current

REVERSE DRAIN CURRENT: lor (A)

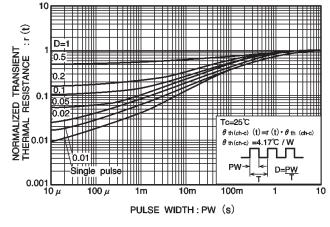
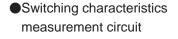


Fig.15 Normalized transient thermal resistance vs. pulse width



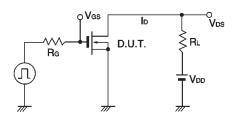


Fig.16 Switching time measurement circuit

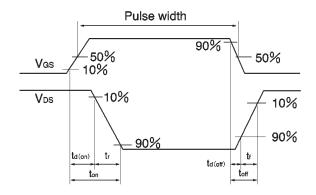


Fig.17 Switching time waveforms

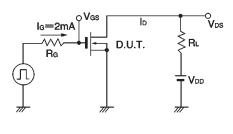


Fig.18 Gate charge measurement circuit



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Appendix

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